Laser spectroscopy with Diode Lasers

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Application domain of Laser Spectroscopy

- Spectroscopy of atoms, molecules, ions, clusters:
 - Energy levels (electronic, vibration, rotation)
 - Lifetime of states
 - Collisional properties of the levels
- Determination of species density & temperature (abs.)
 Optical saturation phenomena
- Other artifacts encountered in Laser Spectroscopy

Principle of Laser Spectroscopy



Either in Laser Absorption or in Laser Induced Fluorescence techniques, spectral information comes from the first step:

absorption of photons

Principle of Laser Spectroscopy



-From absorption signal

 $Ln(\frac{I_0(\nu)}{I(\nu)}) = l.\alpha(\nu)$

$$I_{LIF}(\nu) \approx \Phi(P_{Laser}).\alpha(\nu)$$

Absorption Coefficient

$$\alpha(\nu) = \frac{4hB_{12}}{\lambda\gamma} \left(n_1(\nu) - \frac{g_1}{g_2} n_2(\nu) \right)$$

What can we learn by measuring $\alpha(v)$?



Density and Temperature of Ar^{*} atoms in a high density pulsed Helicon discharge





Units used in spectroscopy

 $1 \text{ eV} = 1.6 \text{ x } 10^{-19} \text{ J} = 8065 \text{ cm}^{-1}$ Wavenumber $300 \text{ kT} = 207 \text{ cm}^{-1}$ $1 \text{ cm}^{-1} = 30 \text{ GHz}$

$$\nu = \frac{c}{\lambda}$$
 $\Delta \nu = \frac{c * \Delta \lambda}{\lambda^2}$

Photon energy:

At 563 nm,

 $\lambda = 500 \text{ nm}$ $1/\lambda = 20000 \text{ cm}^{-1}$

Linewidth:

 $\Delta \lambda = 1 \text{ nm} \rightarrow \Delta \nu = 1000 \text{ GHz}$

Spectral line profiles

Homogeneous linewidth: For a given transition it is identical for all atoms:

Its shape is a Lorentzian

Natural linewidth:

Power broadening:

$$\delta v_n(FWHM) = \frac{1}{2\pi\tau}$$

 $\delta v_{\rm S} = \delta v_n \sqrt{1 + S_0}$ S₀ at the line center v₀

 $\phi_L(v-v_0) = \frac{1}{2\pi} \frac{\delta v_L}{(v-v_0)^2 + (\delta v_L/2)^2}$

Inhomogeneous linewidth: results from collective effects, for example thermal motion of atoms (**Doppler broadening**):

Its shape is a Gaussian

$$\phi_D(\nu - \nu_0) = \frac{2\sqrt{\ln(2)/\pi}}{\delta \nu_D} \exp(-4\ln(2) \frac{(\nu - \nu_0)^2}{(\delta \nu_D)^2}$$

Doppler linewidth: $\delta v_D(GHz) = (2v_0/c)\sqrt{2\ln 2(RT/M)} = 7.16 \cdot 10^{-16} v_0 \sqrt{T/M}$

For sodium 589.1 nm line (τ =16 ns) at 500 K:

 $\delta v_n = 0.01 \text{ GHz}$ $\delta v_D = 1.7 \text{ GHz}$

Different type of Lasers

- **Frequency fixed:** (often used as pump laser)
- Ar⁺, Kr⁺, Nd-Yag, Excimer (XeCl), Cu, HeNe $\Delta v_L \cong 10 \text{ GHz}$

Tunable lasers:

- <u>Pumped by a laser</u>: Dye, Ti:Sa, OPO (tuning range 10 to 100 nm)
 Lasers available from 400 nm to µm (+ frequency doubling)
 - * Pulsed lasers: P up to 10 mJ, $\Delta t \approx 3$ to 30 ns, $\Delta v_L \ge 1$ GHz Convenient for frequency doubling and n photon transitions * CW lasers: P= up to a few W, $\Delta v_L \approx 0.001$ GHz Convenient for high resolution spectroscopy
- Diode laser: lasers available from 400 nm to 10 µm with
 - * tuning range up to 10 nm

* P= up to a few 10 mW, $\Delta v_L \approx 0.001$ GHz (if single mode) They are more compact, easier to run and cheaper



* Complex line structures result from Isotope Shifts and Hyperfine Structure.

- * Power saturation on 823.1 nm line because $Xe^{*}(^{3}P_{2})$ depletion. * No saturation on 828 nm line because $Xe^{*}(^{3}P_{1})$ lifetime $\cong 10$ ns

Origin of optical saturation

$$\alpha(\nu) = \frac{4hB_{12}}{\lambda\gamma} \left(n_1(\nu) - \frac{g_1}{g_2} n_2(\nu) \right)$$

α becomes no more proportional to n₁

- 1- Laser beam transfers a significant number of atoms from the lower to the upper state and n₂ becomes no more negligible compared to n₁. (short pulse lasers)
- 2- Atoms in the upper state are lost by radiation, or collisional transfers, to a 3rd state and atoms in the lower state are not renewed fast enough: the lower state becomes depleted. (cw lasers)

Rate equations governing the population densities N_1 and N_2 of states $|1\rangle$ and $|2\rangle$ are:

$$\frac{dN_{1}}{dt} = (B_{21}\rho + A_{21})N_{2} - (B_{12}\rho + 1/\tau_{1} + \sum_{q} k_{1,q}M_{q})N_{1} + C_{1}$$
$$\frac{dN_{2}}{dt} = B_{12}\rho N_{1} - \left(B_{21}\rho + A_{21} + A_{23} + \sum_{q} k_{2,q}M_{q}\right)N_{2} + C_{2}$$

 $B_{21} = \frac{g_1}{g_2} B_{12} = \frac{\lambda_0^3}{8h\pi} A_{21}$ is the Einstein coefficient for stimulated emission we assume $g_1 = g_2$, ρ is the energy density of the beam,

 C_i accounts for the repopulation of state $|i\rangle$ from different paths, including diffusion transport into the laser volume and radiative cascades

$$\Re_1 = 1/\tau_1 + \sum_q k_{1,q} N_q \qquad \text{and} \qquad \Re_2 = \sum_{i=lower} A_{2i} + \sum_q k_{2,q} N_q$$

are the total relaxation rates of the states

in steady state, $(dN_i/dt=0)$ the density difference of states $|1\rangle$ and $|2\rangle$ is:

$$\Delta N = N_1 - gN_2 = \Delta N^0 / (1 + S \frac{\Re_2 - A_{21} + g \Re_1}{\Re_1 + \Re_2})$$

Where $\Delta N^0 = N_1^0 - gN_2^0 = \frac{C_1}{\Re} - \frac{C_2}{\Re} (g - A_{21}/\Re)$ is in the absence of laser beam ($\rho = 0$),

and

$S=B_{12}\rho/\Re^*$ is **The saturation parameter**

related to the mean relaxation rate

 $\mathfrak{R}^* = \mathfrak{R}_1 \mathfrak{R}_2 / (\mathfrak{R}_1 + \mathfrak{R}_2)$

The resulting population density in the lower state is:

$$N_{1} = \frac{C_{1}(gS + R_{2}/\Re^{*}) + C_{2}(gS + A_{21}/\Re^{*})}{S[R_{2} - A_{21} + gR_{1}] + (R_{1} + R_{2})} \quad \text{When} \quad N_{1} = \frac{C_{1}(gS + R_{2}/\Re^{*})}{C_{2 \rightarrow 0}}$$

Larger S is, lower the measured population will be

When
$$\rho \to 0$$
, $N_1 = \frac{C_1}{\Re_1}$ For $\rho \to \infty$ $N_1 = \frac{g(C_1 + C_2)}{\Re_2 - A_{21} + g \Re_2}$

Estimation of saturation parameter S For a cw laser: 2

 λ = 590 nm ;

 $\tau_2 = 16 \text{ ns}$; hence $R_2 = 1/\tau_2 = 6.25 \ 10^7 \text{ s}^{-1}$

But $A_{21}=6\ 10^6\ s^{-1}$;

 $R_1 = (1/\text{transit time inside a beam of } \phi = 2 \text{ mm}) = (0.5 \text{ km.s}^{-1})/(2 \text{ mm}) = 2.5 \text{ 10}^5 \text{ s}^{-1}$

Laser power: P=1 mW;

 $\Delta v_{\rm L} = 1 \text{ MHz} << 1/(2\pi\tau_2);$

Laser beam diameter =2 mm

We can calculate

$$S = \frac{B_{12} * \rho}{R_1} = 20$$

Hence the density measured by absorption will not be correct with so large S value because $N_1 = N_1^0/(1+S)$ However, as $\delta_{V_S} = \delta_V * \sqrt{1+S} = 4.5 * \delta_V = 45$ MHz is much smaller than the Doppler width (1.7 GHz), the line profile can still provide the gas temperature

Line Profiles Broadened by pressure (800 mBar)

Xe 823nm line :

⇒Lorentzian profile with $\Delta v=7,2$ GHz, shifted by -1,1 GHz

Xe 828 nm line :

⇒Lorentzian profile with $\Delta v=16,8$ GHz, shifted by -0,72 GHz



Line profile in presence of magnetic field in a low power Helicon Argon plasma; p= 0.9 to 10 µbar



Line profile in presence of strong magnetic field

Zeeman components of the absorbing lines of Argon





- if $\vec{E} \perp \vec{B}$ only σ^+ and σ^- lines exist $\vec{k} \perp \vec{B}$
- $\vec{k} \perp \vec{B}$ $\vec{E}/(\vec{B})$ only π line (s) exist if
- then only σ^+ and σ^- lines exist \vec{k}/\vec{B}

Experimental profiles of the 722.38 nm line with two different polarization fitted with Gaussians



Concluding remarks concerning measurements by laser absorption techniques

For density measurements

- * Laser intensity must be very low to avoid optical saturation:
 - $P \le 1 \mu W / mm^2$ for an strong atomic line.
- For CRDS, the laser power inside the cavity must be considered For gas temperature measurements
- * Atoms in interaction with the laser beam must be in collisional equilibrium with the gas bath and their mean free path much shorter than the vessel dimensions.



Experimental determination of argon atoms *vdf* in an expanding arc jet by LIF (Eindhoven)



Laser Doppler-Shift setup



Ar^{*} velocity distribution functions



Equipement commun du Réseau Plasmas Froids **''Système Laser à Diode''** acquis sur les crédits MRCT – CORTECH **Total des crédits reçus (2004-2007): 49551 €**

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- Matériel: lasers avec cavité externe du type Littrow et du type DFB fournissant qqs 10 mW continus dans une largeur spectrale d'environ 10 MHz ($\cong 10^{-5}$ nm)

- Fournisseur: TOPTICA, représenté par OLI

DL avec cavité externe acquis par RPF

Ces DL avec cavité externe (Littrow) sont balayables sur environ une vingtaine de GHz sans saut de mode (ssm). L'accord en longueur d'onde sur la gamme de fonctionnement est obtenu en changeant la température de la DL.

- 1 Électronique de commande (Sys DL 100/19), avec: contrôle de courant, contrôle de température et tiroir de modulation (géné de fréquence).
- 5 Têtes laser:

_	1059 – 1090 nm;	30 mW;	15 GHz (ssm)	He*, N ₂ *	k
_	750 – 791 nm;	30 mW;	30 GHz	(ssm)	Ar*, 0*
—	652 – 662 nm;	30 mW;	20 GHz	(ssm)	H *
—	402 – 407 nm	10 mW	20 GHz	(ssm)	Ga
—	396 – 399 nm;	10 mW;	20 GHz	(ssm)	Ti, Al

DL du type DFB acquis par RPF

Ces DL sont sans cavité externe mais ont un réseau de Brag intégré. Leur domaine d'accordabilité n'est que d'environ 1 nm. Le balayage en fréquence peut être obtenu par le courant (environ 20 GHz ssm) ou par la température (très lent <Hz mais sur toute la gamme: environ 1 nm \cong 1000 GHz ssm). La stabilité en fréquence n'est que \cong 200 MHz sur quelques minutes (\cong 20-50 MHz pour DL Littrow) mais convient pour raies élargies à haute pression.

•1 Électronique de commande (Sys DL- DFB 100/19), avec: contrôle de courant, contrôle de température et tiroir de modulation (géné de fréquence).

•2 Têtes laser:

- 772 773 nm; 70 mW; 20 GHz (ssm) Ar*
- 1081 1083 nm; 70 mW; 20 GHz (ssm) He*

Matériels d'accompagnement:

- 1 Barreau en verre de 10 cm avec faces parallèles polies pour servir d'étalon Fabry-Perot ayant un intervalle spectral libre de l'ordre de 1 GHz
- 1 Lambdamètre devant permettre la mesure de longueur d'onde avec une précision de 3 pm. L'injection par une fibre optique monomode pose toujours quelques problèmes.
- 3 photodiodes; sensibilité≅ 1V/µW; bande passante 15 kH

Intensity of Laser Induced Fluorescence signal

LIF signal is proportional to N₂ density given by:

$$I_{23} \propto N_2 A_{23} \propto N_1 (El, V, R) A_{23} \frac{B_{12} \rho}{B_{21} \rho + \Re_2}$$

When LIF is used to determine the relative population of two different especies, m and n:

At low laser power limit, the LIF signal ratio is:

 $\frac{I_{23}(m \to 3)}{I_{23}(n \to 3)} = \frac{N_1(i)}{N_1(j)} \frac{B_{im}}{B_{jn}} \frac{A_{m3}}{A_{n3}} \frac{\tau_m}{\tau_n} \quad \textbf{t could be p and T dependent}$

At high laser power limit, the LIF signal ratio is:

$$\frac{I_{23}(m \to 3)}{I_{23}(n \to 3)} = \frac{N_1(i)}{N_1(j)} \left(\frac{g_i}{g_m}\right) \left(\frac{g_n}{g_j}\right) \frac{A_{m3}}{A_{n3}}$$